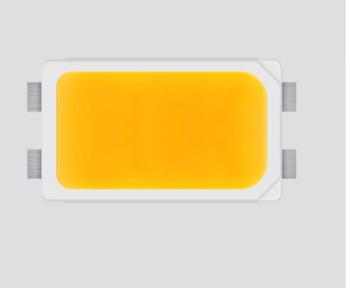
# Middle Power LED Series 5630

## LM561C



LM561C is highest performance and Im/W for fluorescent replacement







#### **Features & Benefits**

- 0.3 W class middle power LED
- Mold resin for high reliability
- Standard form factor for design flexibility (5.6  $\times$  3.0 mm)



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## 1. Characteristics

## a) Absolute Maximum Rating

ltem	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	Ta	-40 ~ +85	°C	-
Storage Temperature	$T_{stg}$	-40 ~ +120	°C	-
LED Junction Temperature	Tj	110	°C	-
Forward Current	l <sub>F</sub>	200	mA	-
Peak Pulsed Forward Current	l <sub>fp</sub>	300	mA	Duty 1/10, pulse width 10 ms
Assembly Process Temperature	_	260 <10	°C s	-
ESD (HBM)	_	±5	kV	-



## b) Electro-optical Characteristics (I<sub>F</sub> = 65 mA, $T_s$ = 25 °C)

ltem	Unit	CRI (R₃) Min.	Nominal CCT (K)	Rank	Bin	Min.	Тур.	Max.
					AY	2.6	-	2.7
Forward Voltage (V <sub>F</sub> )	V			XA	AZ	2.7	_	2.8
					A1	2.8	-	2.9
Luminous Flux (Φ <sub>v</sub> )	lm	80	5000		S5	35.0	-	37.0
Eurinous Flux (\$\psi_y)	1111	00			S6	37.0	-	39.0
Reverse Voltage (@ 5 mA)	V					0.7	-	1.2
Color Rendering Index (Ra)	-			5		80	-	-
Special CRI (R9)	-					0	_	_
Thermal Resistance (junction to solder point)	°C/W					-	14	20
Beam Angle	o					-	120	-

#### Note:

Samsung maintains measurement tolerance of: forward voltage =  $\pm 0.1$  V, luminous flux =  $\pm 5$  %, CRI =  $\pm 3$ , R9 =  $\pm 6.5$ 



## 2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	Р	М	w	н	т	5	4	1	М	L	5	Х	K	S	K	S	5

Digit	Digit PKG Information		Specification			
1 2 3	Samsung Package Middle Power	SPM				
4 5	Color	WH	White			
6	Product Version	Т				
7 8 9	Form Factor	541	5.6 x 3.0 x 0.7 mm; 4 pads; LM561C			
10	Sorting Current (mA)	М	65 mA			
11	Chromaticity Coordinates	L	Ansi Standard			
12	CRI	5	Min. 80			
13 14	Forward Voltage (V)	XA XK	2.6~2.9V (2,500 pcs/Reel) 2.6~2.9V (10,000 pcs/Reel)			
15 16	CCT (K)	S☆	5000 Bin Code: R6, R7, R8, S5, RA, RB, RC, S9, RE, RF, RG, SD, RU, RV, RW, ST  ☆: "0" (Whole bin) "M" (Quarter bin), "K" (K Kitting), "N""(S Kitting) or "G"(L Kitting)			
17 18	Luminous Flux	S0 S5 S6	Bin S5 Code: S6			



## a) Luminous Flux Bins(I<sub>F</sub> = 65 mA, T<sub>s</sub>= 25°C)

CRI (R₃) Min.	Nominal CCT (K)	Product Code	Flux Bin	Flux Range (Φ <sub>v</sub> , lm)
00	5000	SPMWHT541ML5X♠S☆S5	S5	35.0 ~ 37.0
80	5000	SPMWHT541ML5X∳S☆S6	S6	37.0 ~ 39.0

#### Note:



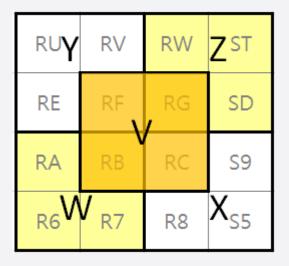
<sup>&</sup>quot; $\spadesuit$ " can be "A" (2,500pcs) or "K" (10,000pcs) of reel taping

#### b) Kitting rule

#### 1) K Kitting Concept

- 1. Under agreement between customer and SAMSUNG ELECTRONICS, SAMSUNG can supply kitting bin (VF, Color, Im).
- 2. A forward voltage (VF) of kitting bin is combined by a pair of same VF rank such as (A1+A1), (AY+AY) or (AZ+AZ).
- 3. A Chromaticity Coordinates of kitting bin is mixed by kitting procedure.(below kitting simulation)

#### [Kitting example]



## [Binning Information]

	Bin #1	Bin #2	Priority
	AY	AY	
VF	AZ	AZ	
	A1	A1	
	W	Z	
CIE	V	V	
	X	Υ	
N /	<b>S</b> 5	<b>S</b> 5	S5↑
IV	S6	S6	S6↑

※ Each of V,W,X,Y and Z can be one bin without details division.



#### 2) N Kitting Concept

- 1. Under agreement between customer and SAMSUNG ELECTRONICS, SAMSUNG can supply kitting bin (VF, Color, Im).
- 2. A forward voltage (VF) of kitting bin is combined by a pair of same VF rank such as (A1+A1), (AY+AY) or (AZ+AZ). Chromaticity Coordinates of kitting bin is mixed by kitting procedure.(below kitting simulation)

#### [Kitting example]

RU	RV	RW	ST
RE	RF	RG	SD
RA	RB	RC	<b>S</b> 9
R6	R7	R8	S5

#### [Binning Information]

	Bin #1	Bin #2	Priority
	AZ	AZ	
	A1	A1	
VF	A2	A2	
	A3	A3	
	A4	A4	
O.E.	В	G	
CIE	С	F	
	S5	<b>S</b> 5	S5↑
IV	S6	S6	S6↑

.  $\times$  Each of V,W,X,Y and Z can be one bin without details division.



#### 3) G Kitting Concept

- 1. Under agreement between customer and SAMSUNG ELECTRONICS, SAMSUNG can supply kitting bin (VF, Color, Im).
- 2. A forward voltage (VF) of kitting bin is combined by a pair of same VF rank such as (A1+A1), (AY+AY) or (AZ+AZ). Chromaticity Coordinates of kitting bin is mixed by kitting procedure.(below kitting simulation)

#### [Kitting example]

RU	RV	RW	ST
RE	RF	RG	DS
RA	RB	RC	S9
R6	R7	R8	S5

#### [Binning Information]

	Bin #1	Bin #2	Priority
	AY	AY	
VF	AZ	AZ	
	A1	A1	
	R6	ST	
	R7	RW	
	R8	RV	
O.F.	S5	RU	
CIE	RA	SD	
	RB	RG	
	RC	RF	
	S9	RE	
N /	<b>S</b> 5	<b>S</b> 5	S5↑
IV	S6	S6	S6↑

※ Each of V,W,X,Y and Z can be one bin without details division.



## c) Color Bins ( $I_F = 65$ mA, $T_s = 25$ °C)

CRI (R₃) Min.	Nominal CCT (K)	Product Code	Color Rank	Chromaticity Bins
		SPMWHT541ML5X♦S0S★	S0 (Whole bin)	R6, R7, R8, S5, RA, RB, RC, S9, RE, RF, RG, SD, RU,
	SPMWHT541ML5X♦SGS★  (S Kitting)  5000  SPMWHT541ML5X♦SMS★  SM (Quarter bin)  SPMWHT541ML5X♦SKS★  SK (K Kitting)  SV, S	RV, RW, ST		
80			RB, RC, RF, RG	
		SPMWHT541ML5X♦SKS★		SV, SW, SX, SY, SZ
		SPMWHT541ML5X♦SNS★		RB, RC, RF, RG

#### Note:

" $\spadesuit$ " can be "A" (2,500pcs) or "K" (10,000pcs) of reel taping

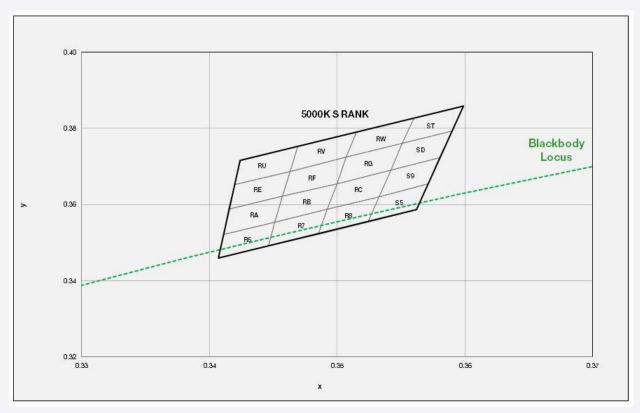
## d) Voltage Bins ( $I_F = 65 \text{ mA}$ , $T_s = 25 \,^{\circ}\text{C}$ )

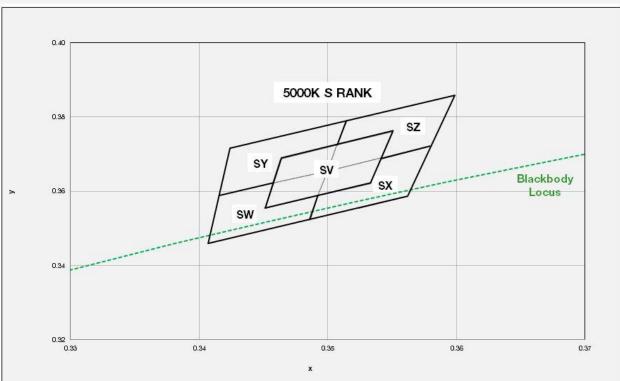
CRI (R₃) Min.	Nominal CCT (K)	Product Code	Voltage Rank	Voltage Bin	Voltage Range (V)
				AY	2.6 ~ 2.7
-	-	-	XA	AZ	2.7 ~ 2.8
			***	A1	2.8 ~ 2.9



<sup>&</sup>quot;★" can be "S5" or "S6" of luminous flux bin

## e) Chromaticity Region & Coordinates (IF = 65 mA, Ts = 25 °C)







## e) Chromaticity Region & Coordinates (IF = 65 mA, $T_s$ = 25 °C)

Region	CIEx	CIE y	Region	CIE x	CIE y		
S rank (5000K)							
	0.3407	0.346		0.3415	0.3587		
DC	0.3411	0.3522	DE.	0.342	0.3652		
R6	0.3451	0.3554	RE	0.3463	0.3687		
	0.3446	0.3491		0.3457	0.3621		
	0.3446	0.3491		0.3457	0.3621		
	0.3451	0.3554		0.3463	0.3687		
R7	0.3492	0.3587	RF	0.3507	0.3724		
	0.3485	0.3522		0.35	0.3655		
	0.3485	0.3522		0.35	0.3655		
-	0.3492	0.3587	5.0	0.3507	0.3724		
R8	0.3533	0.362	RG	0.3551	0.376		
	0.3524	0.3554		0.3542	0.369		
	0.3524	0.3554		0.3542	0.369		
0.5	0.3533	0.362	0.5	0.3551	0.376		
S5	0.3571	0.3655	SD	0.359	0.3792		
	0.3562	0.3586		0.358	0.3723		
	0.3415	0.3587		0.342	0.3652		
DA	0.3411	0.3522	DII	0.3424	0.3715		
RA	0.3451	0.3554	RU	0.3469	0.3752		
	0.3457	0.3622		0.3463	0.3687		
	0.3451	0.3554		0.3463	0.3687		
DD	0.3457	0.3621	DV	0.3469	0.3752		
RB	0.35	0.3655	RV	0.3515	0.379		
	0.3492	0.3587		0.3507	0.3724		
	0.3492	0.3587		0.3507	0.3724		
D.C.	0.35	0.3655	DW	0.3515	0.379		
RC	0.3542	0.369	RW	0.356	0.3827		
	0.3533	0.362		0.3551	0.376		
	0.3533	0.362		0.3551	0.376		
00	0.3542	0.369	<b>CT</b>	0.356	0.3827		
S9	0.358	0.3723	ST	0.3599	0.3859		
	0.3571	0.3655		0.359	0.3792		



## f) Kitting Chromaticity Region & Coordinates

Region	CIE x	CIE y	Region	CIE x	CIE y		
	S rank (5000 K)						
	0.3451	0.3554		0.3415	0.3588		
SV	0.3463	0.3687	SY	0.35	0.3655		
SV	0.3551	0.376	Sĭ	0.3515	0.379		
	0.3533	0.362		0.3424	0.3715		
	0.3407	0.346	SZ	0.358	0.3723		
SW	0.3415	0.3588		0.35	0.3655		
SVV	0.35	0.3655		0.3515	0.379		
	0.3485	0.3524		0.3599	0.3859		
	0.3485	0.3524					
SX	0.35	0.3655					
	0.358	0.3723					
	0.3562	0.3586					

#### Note:

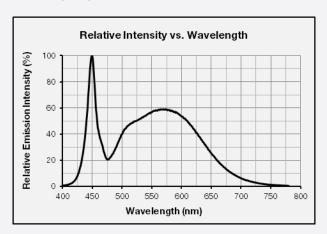
Samsung maintains measurement tolerance of: Cx,  $Cy = \pm 0.005$ 



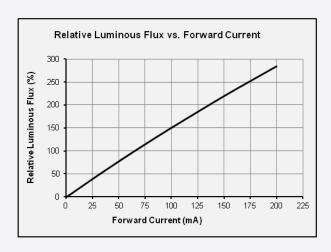
## 3. Typical Characteristics Graphs

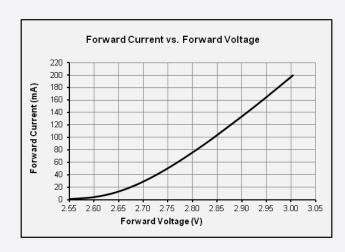
#### a) Spectrum Distribution (I<sub>F</sub> = 65 mA, $T_s$ = 25 °C)

CCT: 5000 K (80 CRI)

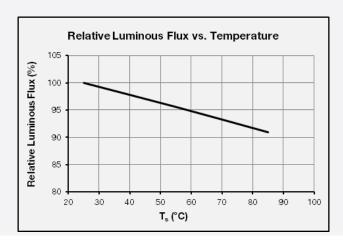


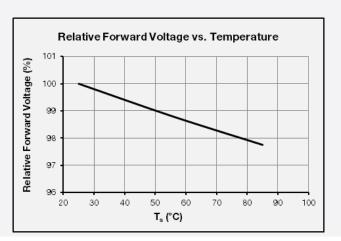
#### b) Forward Current Characteristics (T<sub>s</sub> = 25 °C)





#### c) Temperature Characteristics (I<sub>F</sub> = 65 mA)



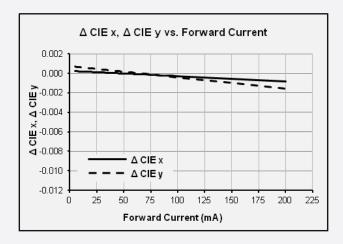


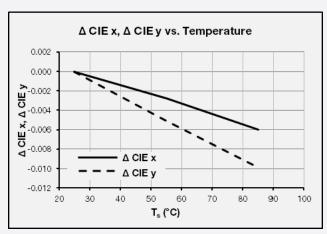


#### d) Color Shift Characteristics

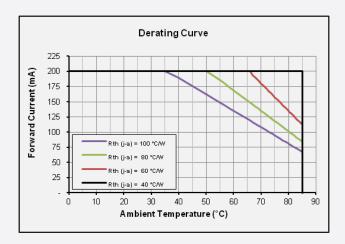
#### T<sub>s</sub> = 25 °C

 $I_F = 65 \text{ mA}$ 

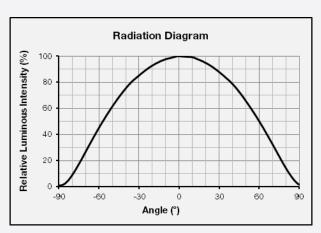




#### e) Derating Curve

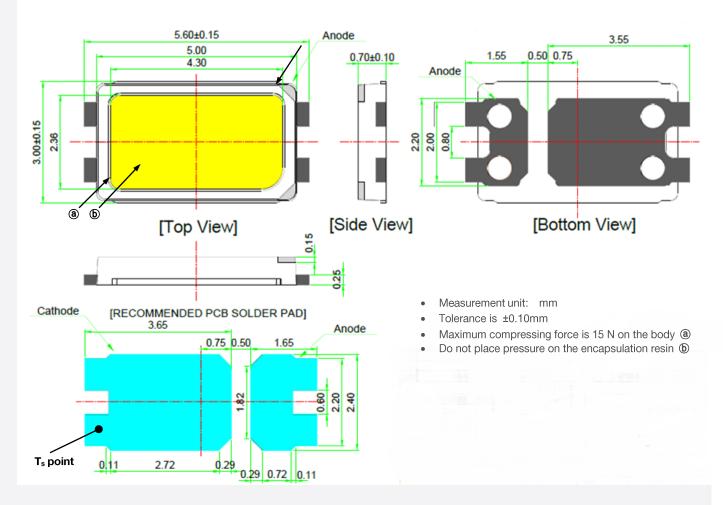


#### f) Beam Angle Characteristics ( $I_F = 65 \text{ mA}$ , $T_s = 25 \,^{\circ}\text{C}$ )





#### 4. Outline Drawing & Dimension



#### Notes:

- 1) This LED has built-in ESD protection device(s) connected in parallel to LED chip(s).
- 2) T<sub>s</sub> point and measurement method:
  - (1) Measure one point at the cathode pad, if necessary remove PSR of PCB to reach Ts point.
  - 2 All pads must be soldered to the PCB to dissipate heat properly, otherwise the LED can be damaged.

#### **Precautions:**

- 1) Pressure on the LEDs will influence to the reliability of the LEDs. Precautions should be taken to avoid strong pressure on the LEDs. Do not put stress on the LEDs during heating.
- 2) Re-soldering should not be done after the LEDs have been soldered. If re-soldering is unavoidable, LED's characteristics should be carefully checked before and after such repair.
- 3) Do not stack assembled PCBs together. Since materials of LEDs is soft, abrasion between two PCB assembled with LED might cause catastrophic failure of the LEDs.



## 5. Reliability Test Items & Conditions

## a) Test Items

Test Item	Test Condition	Test Hour / Cycle	Sample No.
Room Temperature Life Test	25 °C, DC 180 mA	1000 h	22
High Temperature Life Test	85 °C, DC 180 mA	1000 h	22
High Temperature Humidity Life Test	85 °C, 85 % RH, DC 180 mA	1000 h	22
Low Temperature Life Test	-40 °C, DC 180 mA	1000 h	22
Powered Temperature Cycle Test	-45 °C / 20 min ↔ 85 °C / 20 min, sweep 100 min cycle on/off: each 5 min, DC 180 mA	100 cycles	22
Thermal Cycle	-45 °C / 15 min ↔ 125 °C / 15 min → Hot plate 180 °C	500 cycles	100
High Temperature Storage	120 °C	1000 h	11
Low Temperature Storage	-40 °C	1000 h	11
ESD (HBM)	R₁: 10 MΩ R₂: 1.5 kΩ C: 100 pF V: ±5 kV	5 times	30
ESD (MM)	<b>-C</b> R <sub>1</sub> : 10 MΩ R <sub>2</sub> : 0 C: 200 pF V: ±0.5 kV	5 times	30
Vibration Test	20~2000~20 Hz, 200 m/s², sweep 4 min X, Y, Z 3 direction, each 1 cycle	4 cycles	11
Mechanical Shock Test	1500 g, 0.5 ms 3 shocks each X-Y-Z axis	5 cycles	11

## b) Criteria for Judging the Damage

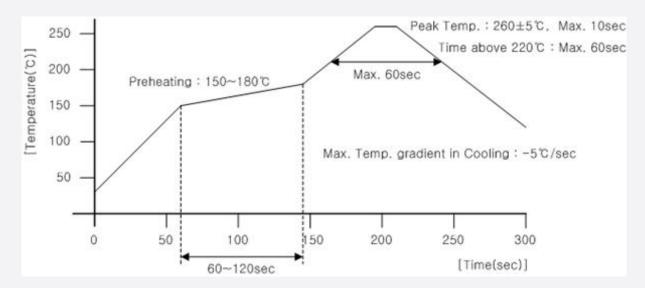
ltem	Symbol	Test Condition	Limit		
item	Зуптоог	$(T_s = 25  ^{\circ}\text{C})$	Min	Max	
Forward Voltage	$V_{F}$	$I_F = 65 \text{ mA}$	Init. Value * 0.9	Init. Value * 1.1	
Luminous Flux	Ф	I <sub>F</sub> = 65 mA	Init. Value * 0.7	Init. Value * 1.1	



## 6. Soldering Conditions

#### a) Reflow Conditions (Pb free)

Reflow frequency: 2 times max.



#### b) Manual Soldering Conditions

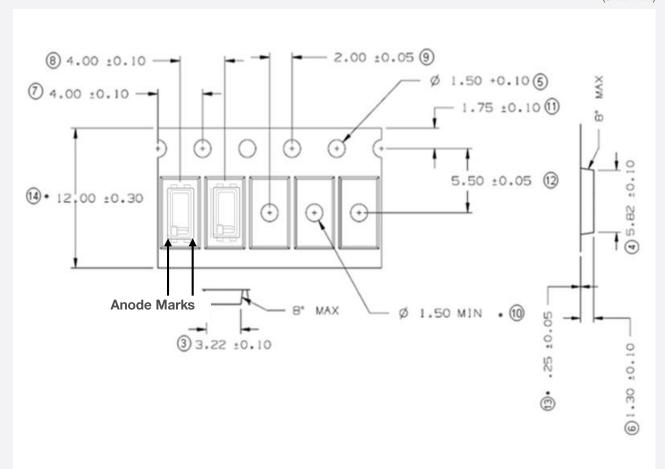
Not more than 5 seconds @ max. 300 °C, under soldering iron.

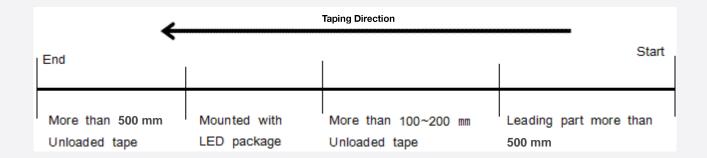


## 7. Tape & Reel

#### a) Taping Dimension

(unit: mm)







#### b-1) Reel Dimension (Max 2,500 pcs)

Ø 180<sup>±0.3</sup>

Ø 180<sup>±0.3</sup>

Ø 10

Ø 10

Ø 10

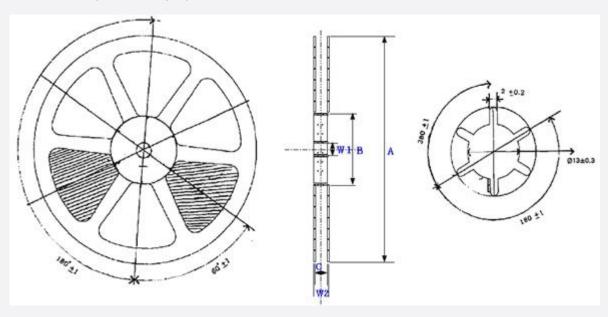
Ø 10

Ø 10

Ø 10

### (unit: mm)

#### b-2) Reel Dimension (Max 10,000 pcs)



Symbol	А	В	С	W1	W2
Spec(mm)	Ø330±1	80±1	13±0.5	13±0.3	17.5±1

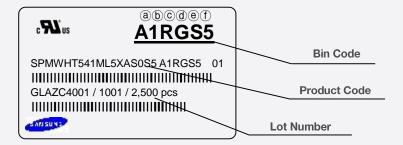
#### Notes:

- 1) Quantity: The quantity/reel is 2,500 or 10,000 pcs
- 2) Cumulative Tolerance: Cumulative tolerance / 10 pitches is  $\pm 0.2 \text{ mm}$
- 3) Adhesion Strength of Cover Tape: Adhesion strength is 0.1-0.7 N when the cover tape is turned off from the carrier tape at 10° angle to the carrier tape
- 4) Packaging: P/N, Manufacturing data code no. and quantity are indicated on the aluminum packing bag



#### 8. Label Structure

#### a) Label Structure



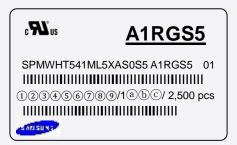
Note: Denoted bin code and product code above is only an example (see description on page 5)

#### Bin Code:

(a) (b): Forward Voltage bin (refer to page 10)(c) (c) (d): Chromaticity bin (refer to page 11-13)(e) (f): Luminous Flux bin (refer to page 6)

#### b) Lot Number

The lot number is composed of the following characters:



123456789 / 1abc / 2,500 pcs

: Production site (S: Giheung, Korea, G: Tianjin, China)

② : L (LED)

3 : Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)

(4) : Year (Z: 2015, A: 2016, B: 2017...)

(5) : Month (1~9, A, B, C)

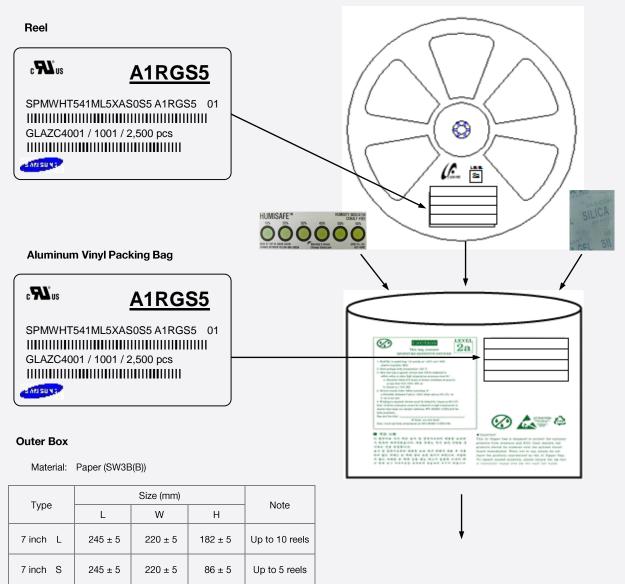
6789 : Day (1~9, A, B~V)

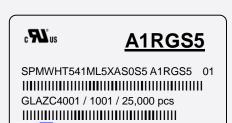
(a)b)c : Product serial number (001 ~ 999)



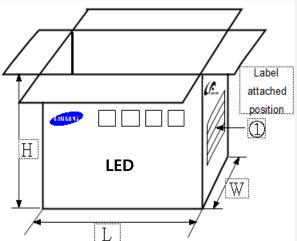
#### 9. Packing Structure

#### a-1) Packing Process (The quantity of PKG on the Reel to be Max 2,500pcs)



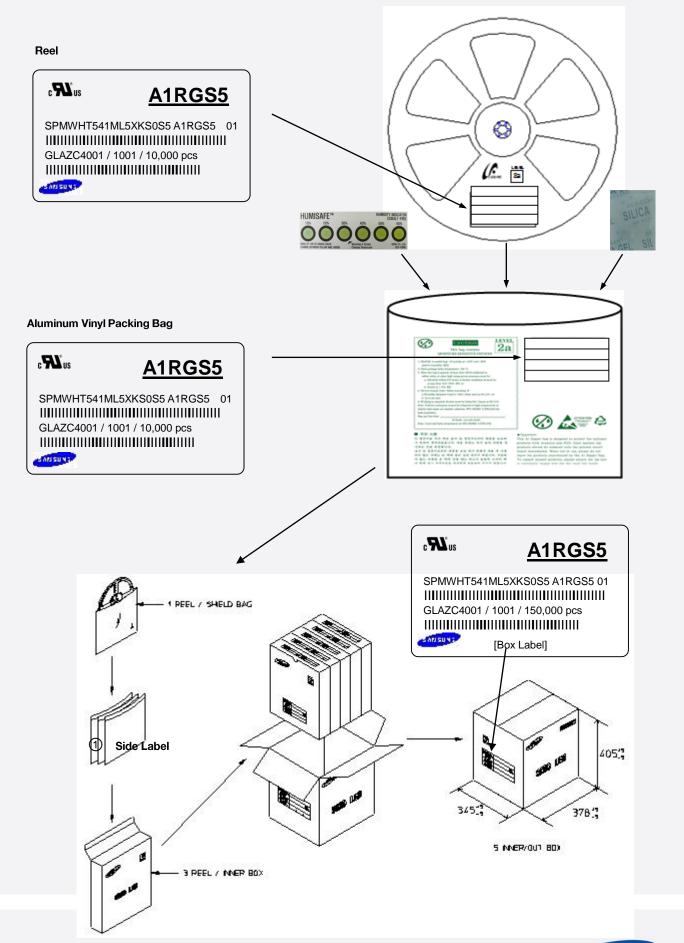


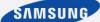
[Box Label]





#### a-2) Packing Process (The quantity of PKG on the Reel to be Max 10,000pcs)

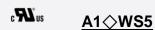




#### b-1) Packing Process for kitting (The quantity of PKG on the Reel to be Max 2,500pcs)

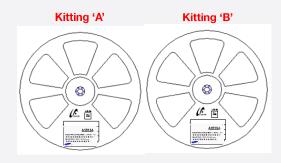
#### Reel

#### Kitting 'A'



#### Kitting 'B'





#### **Aluminum Vinyl Packing Bag**

## Kitting 'A'

c**M**us A1 $\diamondsuit$ WS5

SAME RIVE

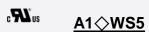
#### Kitting 'B'







#### Kitting 'A'

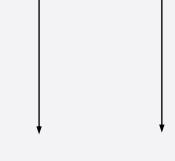


[BOX Label]

#### Kitting 'B'



[BOX Label]

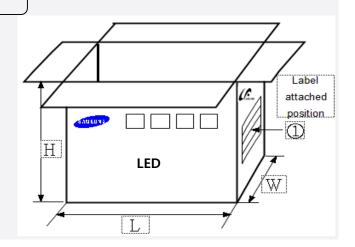


#### Note: "♦" can be Nominal CCT code.

#### **Outer Box**

Material: Paper (SW3B(B))

Time	Size (mm)			Note
Туре	L	W	Н	Note
7 inch L	245 ± 5	220 ± 5	182 ± 5	Up to 10 reels





#### b-2) Packing Process for kitting (The quantity of PKG on the Reel to be Max 10,000pcs)

#### Reel

#### Kitting 'A'

## c**FL**°us

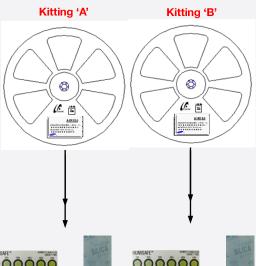
### A1 WS5

SPMWHT541ML5XK KS5 A1 WS5 01

#### Kitting 'B'

### c**FL**°us

A1♦ZS5



#### **Aluminum Vinyl Packing Bag**

#### Kitting 'A'

## c**FL**°us

A1♦WS5

SPMWHT541ML5XK $\diamondsuit$ KS5 A1 $\diamondsuit$ WS5 01

GLAW94001 / 1001 / 10,000 pcs

AZZ SU NZ

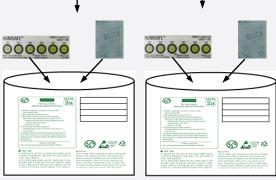
#### Kitting 'B'

## c**FL**°us

A1 **ZS5**SPMWHT541ML5XK KS5 A1 ZS5 01

GLAW94001 / 1001 / 10,000 pcs

- AFFEUND



#### Kitting 'A'

## c**FL**°us

A1 $\diamondsuit$ WS5

SPMWHT541ML5XK $\diamondsuit$ KS5 A1 $\diamondsuit$ WS5 01

[BOX Label]

#### Kitting 'B'



A1⇔ZS5

SPMWHT541ML5XK\circ\KS5 A1\circ\ZS5 01

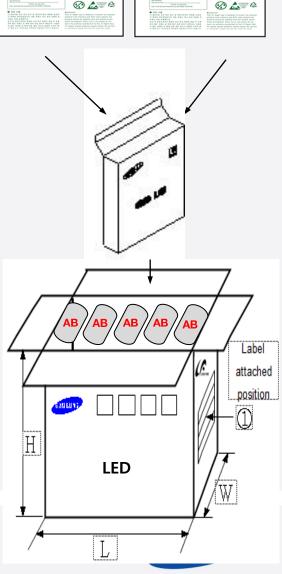
[BOX Label]

Note: "♦" can be Nominal CCT code.

#### **Outer Box**

Material: Paper (SW3B(B))

Typo	Size (mm)			Note
Type	L	W	Н	Note
13 inch L	345 ± 5	378 ± 5	405 ± 5	Up to 10 reels



#### c) Aluminum Vinyl Packing Bag



## CAUTION

# 2a

## This bag contains MOISTURE SENSITIVE DEVICES

- Shelf life in sealed bag: 12 months at <40°C and <90% relative humidity (RH)
- 2. Peak package body temperature: 240 °C
- After this bag is opened, devices that will be subjected to reflow solder or other high temperature processes must be:
  - a. Mounted within 672 hours at factory conditions of equal to or less than 30°C /60% RH, or
  - b. Stored at < 10% RH
- Devices require bake, before mounting, if:

   a. Humidity Indicator Card is > 60% when read at 23±5°C, or
   b. 2. in order of the card is > 100%
- 5. If baking is required, devices must be baked for 10 ~24 hours at 60±5°C Note: if device containers cannot be subjected to high temperature or shorter bake times are desired, reference IPC/JEDEC J-STD-033 for bake procedure,

Bag seal due date:

(if blank, see code label)

Note: Level and body temperature by IPC/JEDEC J-STD-020

## (finalities

c**SL**°us

AN SUNT





A1RGS5

SPMWHT541ML5XAS0S5 A1RGS5 01

GLAZC4001 / 1001 / 2,500 pcs



#### ■ 주의 사항

이 알루미늄 지퍼 백은 습기 및 정전기로부터 제품을 보호하 기 위하여 제작되었습니다. 개봉 후에는 즉시 솔더 작업을 설 시하는 것을 권장합니다.

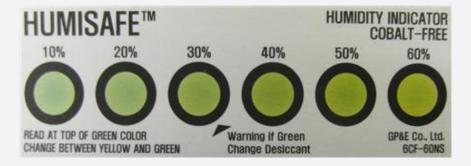
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#### ■ Important

This Al Zipper bag is designed to protect the enclosed products from moisture and ESD. Once opened, the products should be soldered onto the printed circuit board immediately. When not in use, please do not leave the products unprotected by the Al Zipper Bag. To repack unused products., please ensure the zip-lock is completely sealed with the dry pack left inside.

#### d) Silica Gel & Humidity Indicator Card inside Aluminum Vinyl Bag







#### 10. Precautions in Handling & Use

- 1) For over-current protection, users are recommended to apply resistors connected in series with the LEDs to mitigate sudden change of the forward current caused by shift of forward voltage.
- 2) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
- 3) When the device is in operation, the forward current should be carefully determined considering the maximum ambient temperature and corresponding junction temperature.
- 4) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 °C, 0~90 % RH).
- 5) After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
  - a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
  - b. Stored at <10 % RH
- 6) Repack unused devices with anti-moisture packing, fold to close any opening and then store in a dry place.
- 7) Devices require baking before mounting, if humidity card reading is >60 % at 23 ± 5 °C.
- 8) Devices must be baked for  $10\sim24$  hours at  $60\pm5$  °C, if baking is required.
- 9) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or antielectrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
- 11) Risk of sulfurization (or tarnishing)
  - The LED from Samsung uses a silver-plated lead frame and its surface color may change to black (or dark colored) when it is exposed to sulfur (S), chlorine (Cl) or other halogen compound. Sulfurization of lead frame may cause intensity degradation, change of chromaticity coordinates and, in extreme cases, open circuit. It requires caution. Due to possible sulfurization of lead frame, LED should not be used and stored together with oxidizing substances made of materials such as rubber, plain paper, lead solder cream, etc.



## Legal and additional information.

#### About Samsung Electronics Co., Ltd.

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